

Ultra high-speed rectifier diode

1SR159-200

●Applications

High frequency rectification
For switching power supply.

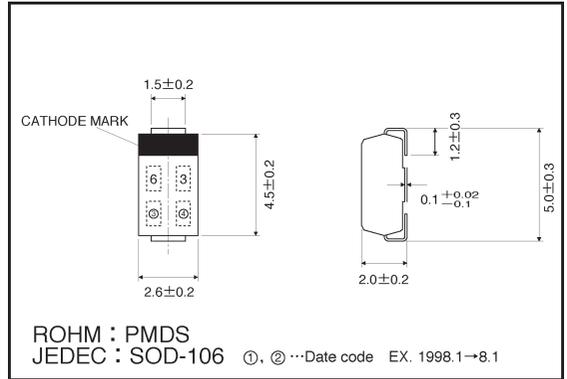
●Features

- 1) Small surface mounting type. (PMDS)
- 2) Low forward voltage. (V_F)
- 3) Reverse recovery time is very fast.
(typical : 23ns)

●Construction

Silicon epitaxial planar

●External dimensions (Units: mm)



●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Absolute peak reverse voltage	V_{RSM}	200	V
Peak reverse voltage	V_{RM}	200	V
Mean rectifying current*1	I_o	1	A
Peak forward surge current*2	I_{FSM}	20	A
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	$-55 \sim +150$	$^\circ\text{C}$

*1 When mounted on an alumina PCB board *2 60 Hz for 1 μs

●Electrical characteristics ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F	—	0.90	0.98	V	$I_F = 1.0\text{A}$
Reverse current	I_R	—	0.6	10	μA	$V_R = 200\text{V}$
Reverse recovery time	t_{rr}	—	23	50	ns	$I_F = I_R = 100\text{mA}$

●Electrical characteristic curves (Ta = 25°C unless specified otherwise)

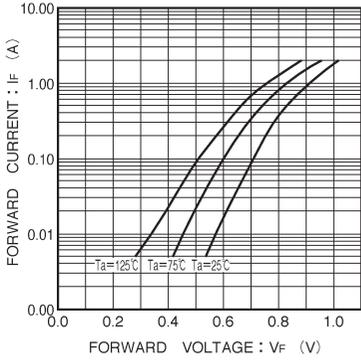


Fig. 1 Forward characteristics

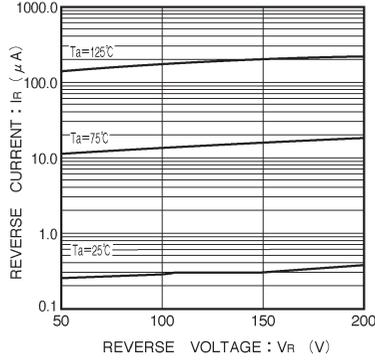


Fig. 2 Reverse characteristics

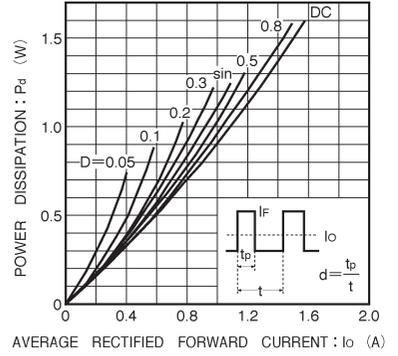


Fig. 3 Power dissipation curves

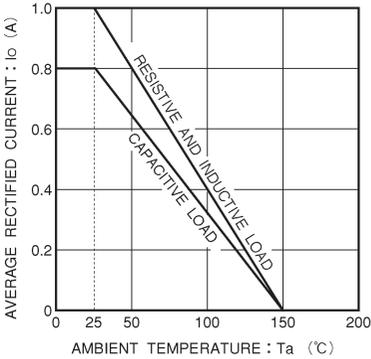


Fig.4 Derating curve

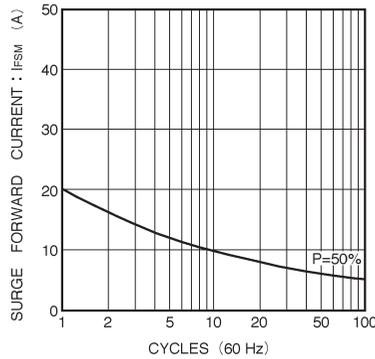


Fig. 5 Maximum peak forward surge current characteristics